

INTEGRATED TRANSFORMERS WITH LAMINATED MAGNETIC CORES

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Outline

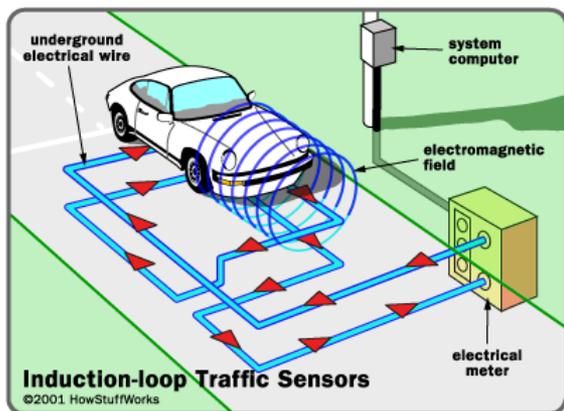
| BACKGROUND | THEORY | MATERIALS | LAYOUT | MEASUREMENTS | RESULTS | CONCLUSION |

- Background
- Theory
- Materials
- Layout
- Measurement
- Results
- Conclusion

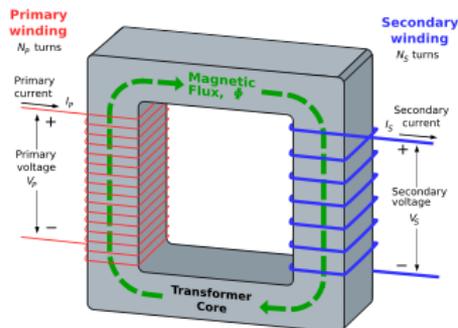
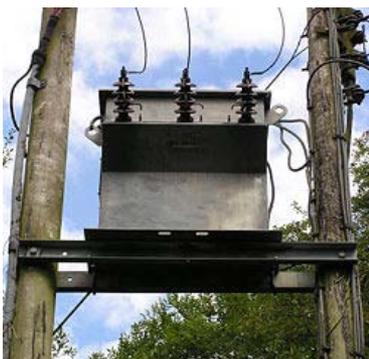
Use of Magnetics in our Everyday Lives

| BACKGROUND | THEORY | MATERIALS | LAYOUT | MEASUREMENTS | RESULTS | CONCLUSION |

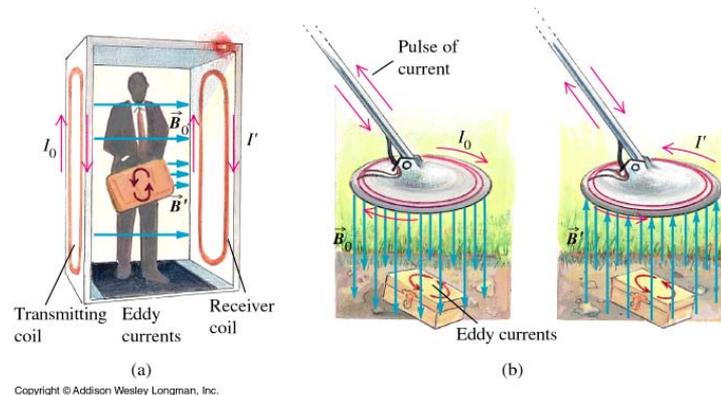
- Traffic lights
- Red-light cameras



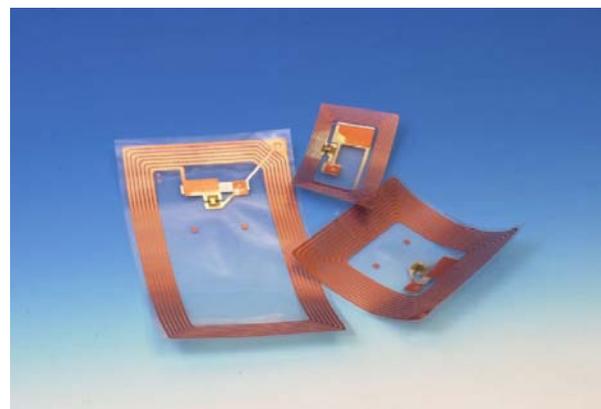
- Transformers



- Metal detectors



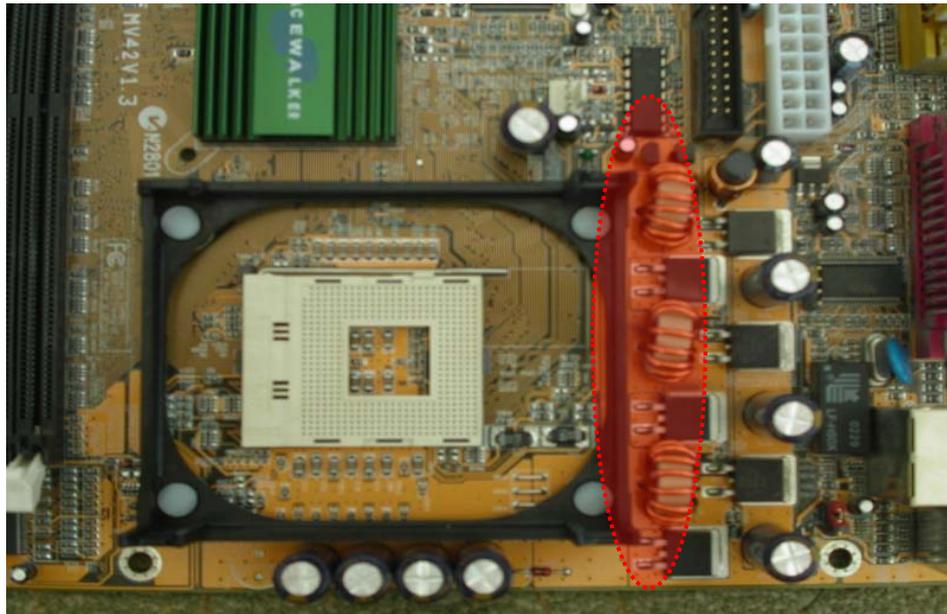
- RFID tags



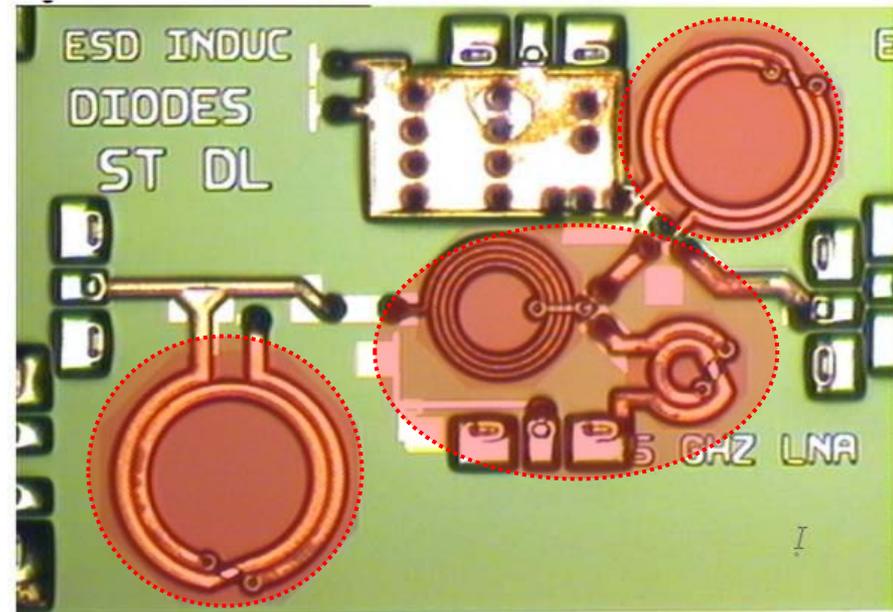
Texas Instruments Tag-it™

And in Electronics...

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Voltage regulator module (VRM)

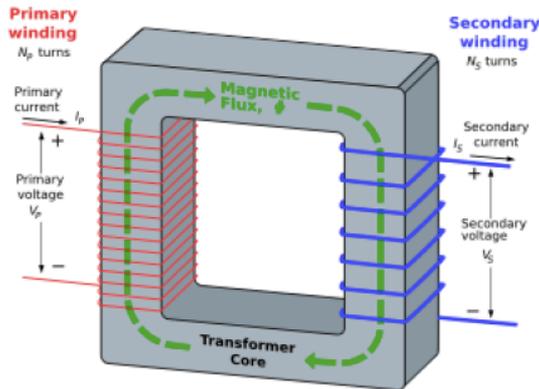


IMEC 5 GHz low noise amplifier

Transformers

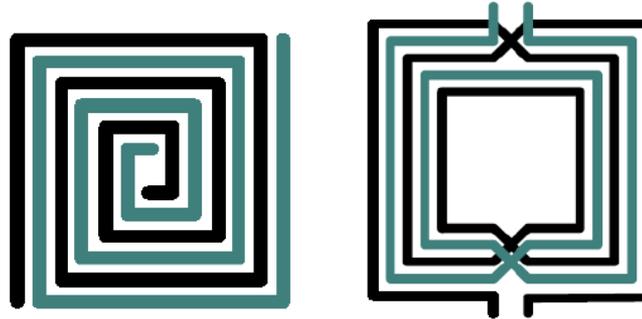
- Transformer: a device that transfers electrical energy from one circuit to another through inductively coupled electrical conductors.

Classical transformer

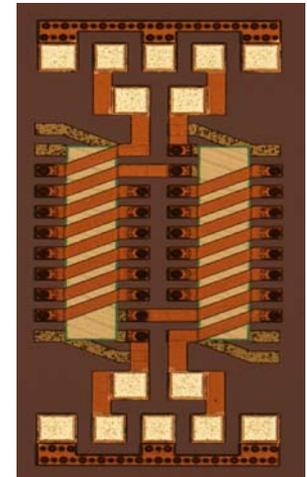


$$\frac{V_S}{V_P} = \frac{N_S}{N_P}$$

Planar spiral transformer



Integrated Solenoid



- A transformer is used for:
 - Voltage gain/reduction using turn ratios between the primary and secondary windings ($V_1/V_2 = N_1/N_2 = I_2/I_1$)
 - Impedance matching through turn ratios ($R_1/R_2 = (N_1/N_2)^2$)
 - Ground isolation, can be performed using a 1:1 transformer, or with various turn ratios for a voltage change.

Transformers vs. Inductors

- Mutual inductance is

$$M = k\sqrt{L_1L_2}$$

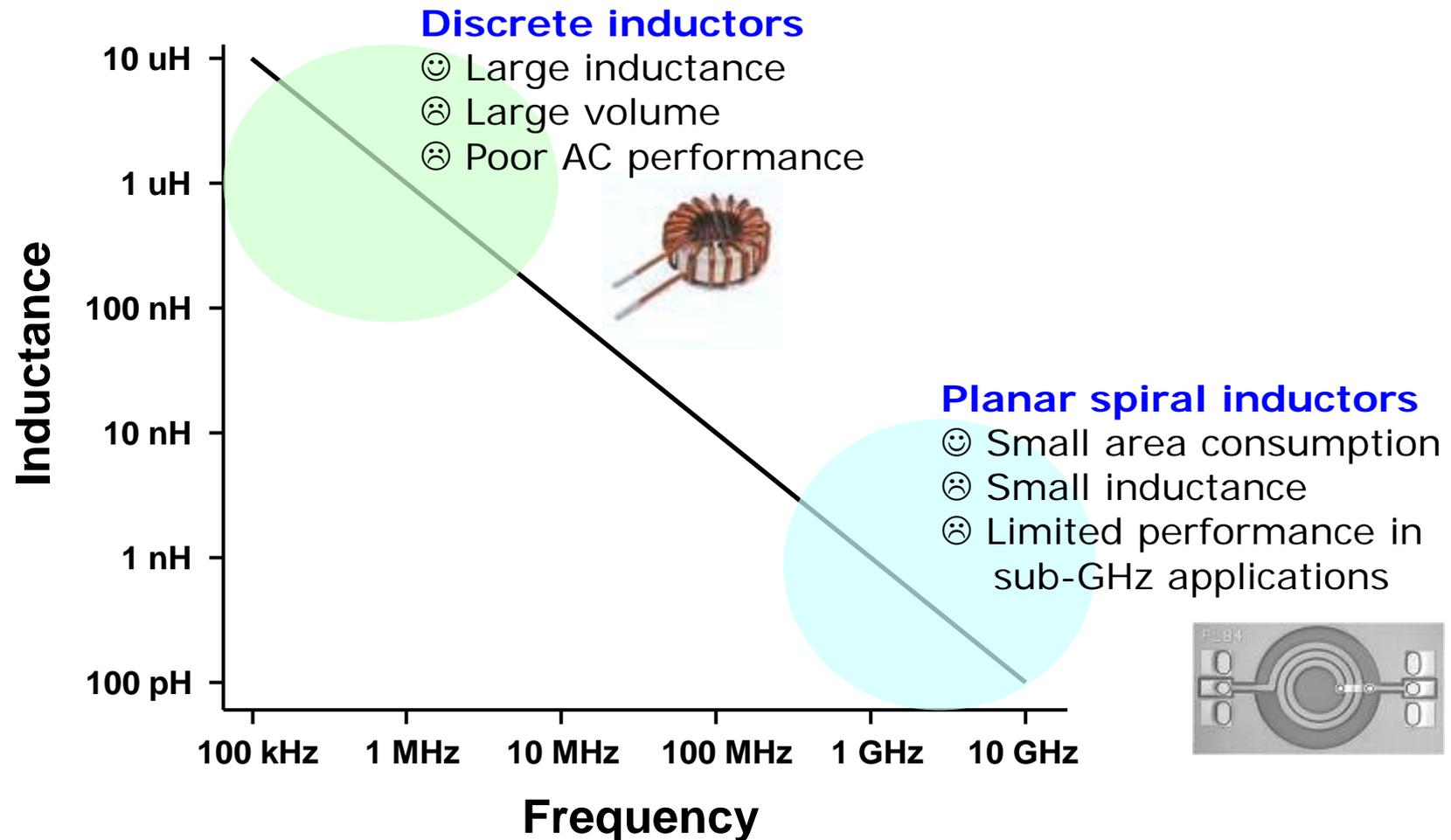
- For 1:1 turn ratio transformers

$$M = kL_1 \text{ if } L_1 = L_2$$

- Large primary and secondary inductances (per area) beget large mutual inductances (per area)!

Inductance & Frequency Tradeoff

| BACKGROUND | THEORY | MATERIALS | LAYOUT | MEASUREMENTS | RESULTS | CONCLUSION |



From A. Ghahary, "Fully integrated DC-DC converters," *Power Electronics Technology*, Aug. 2004

Solenoid Inductance

- Inductance of air core (AC) inductor:

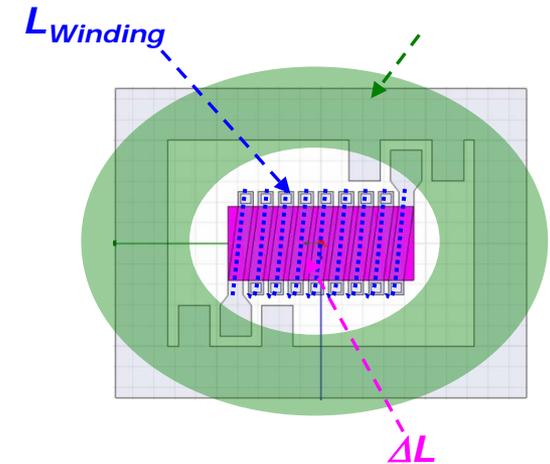
$$L_{AC} = L_{Winding} + L_{Parasitic}$$

- Inductance of magnetic inductor: $L_{MC} = L_{AC} + \Delta L$

- Solenoid inductor:
$$\Delta L = \frac{\mu_0 \mu_r N^2 w_M t_M}{l_M [1 + N_d (\mu_r - 1)]} = \frac{\mu_0 \mu_{eff} N^2 w_M t_M}{l_M}$$

where
$$\mu_{eff} \equiv \frac{\mu_r}{1 + N_d (\mu_r - 1)}$$

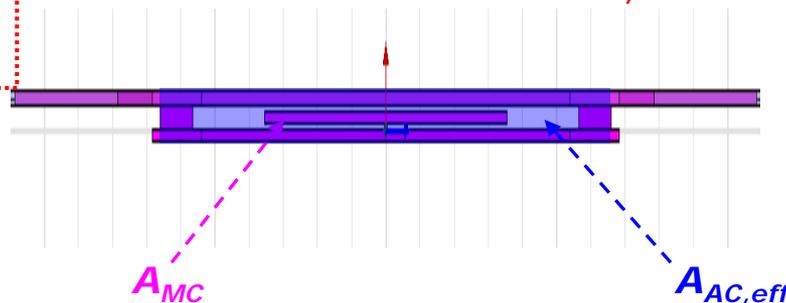
Due to the demagnetization effect



- Inductance enhancement:

$$\frac{\Delta L}{L_{AC}} = \frac{L_{MC} - L_{AC}}{L_{AC}} \approx \mu_{eff} \frac{A_{MC}}{A_{AC,eff}}$$

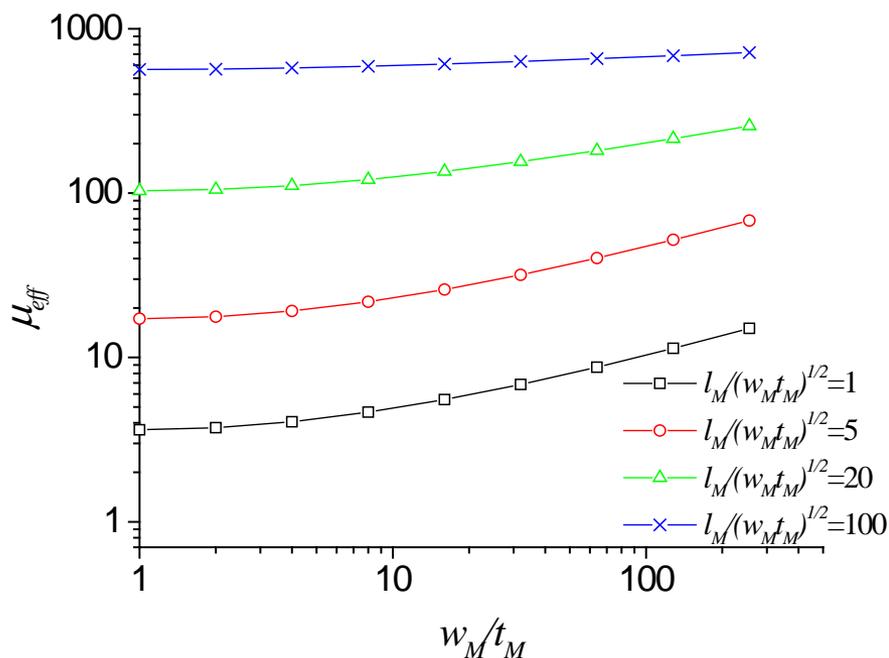
Gain much less than μ_r , but still significant.



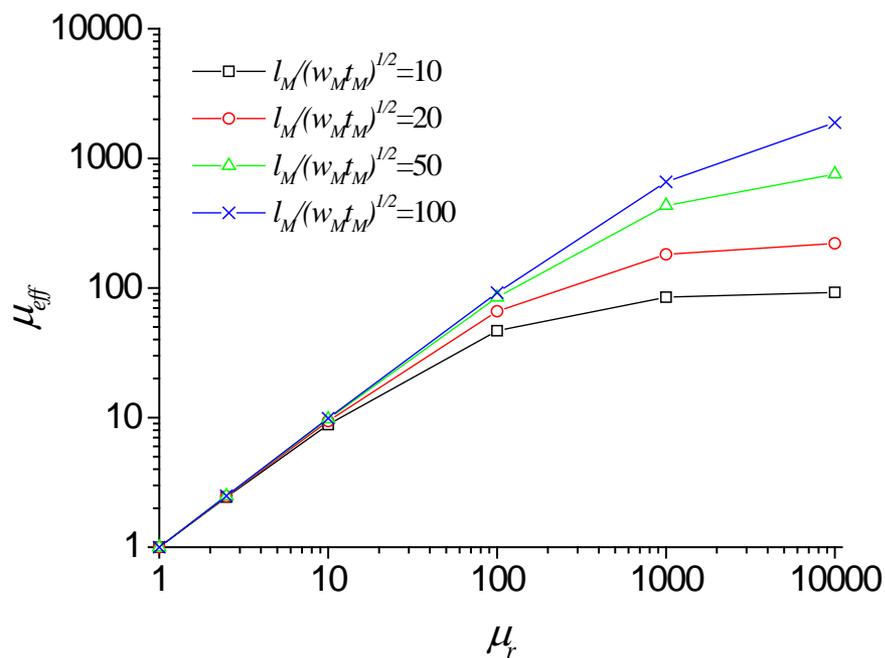
Ref.: D.W. Lee, K.-P. Hwang, S.X. Wang, *IEEE Trans. Mag.*, 44, 4089-95, 2008.

Effective Permeability

$\mu_r = 1000$



$w_M/t_M = 64$



- $l_M \gg (w_M t_M)^{1/2}$ is preferred to maintain a high effective permeability, and greater inductance enhancement.
- The demagnetization effect is more severe for a higher μ_r .

Quality Factor Q & Fundamental Tradeoff

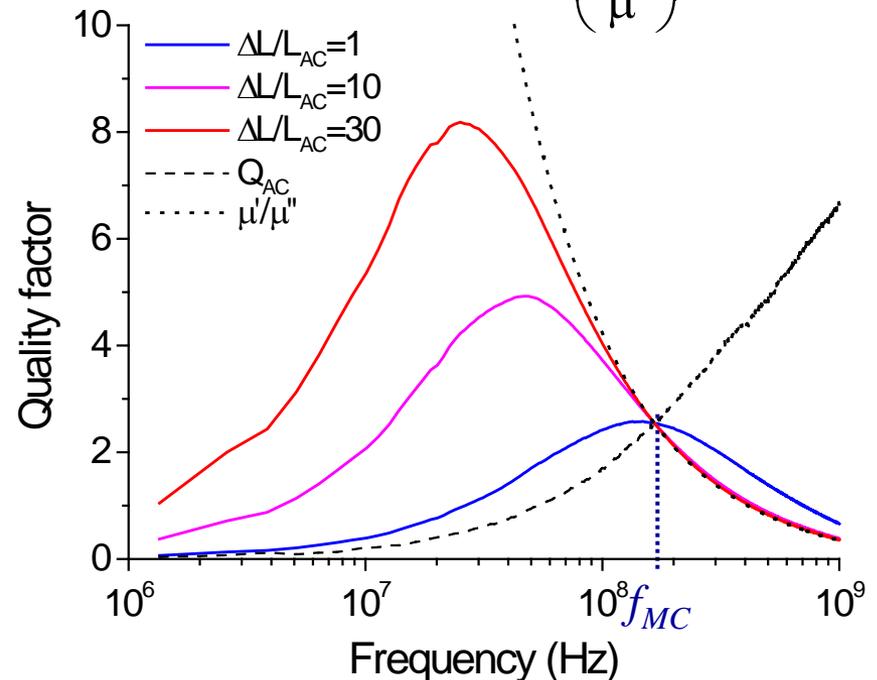
Quality factor of air core inductor: $Q_{AC} = \omega \frac{L_{AC}}{R_{AC}}$

Quality factor of magnetic inductor: $Q_{MC} = \omega \frac{L_{MC}}{R_{MC}} = \omega \frac{L_{AC} + \Delta L}{R_{AC} + \omega \left(\frac{\mu''}{\mu'} \right) \Delta L}$

→ If ΔL is very small, Q_{MC} becomes close to $Q_{AC} = \omega L_{AC}/R_{AC}$. If ΔL is very large compared to L_{AC} , Q_{MC} approaches the permeability ratio μ'/μ'' of the magnetic core.

→ Q_{MC} is higher than Q_{AC} below the frequency f_{MC} at which Q_{AC} and μ'/μ'' cross each other, and Q_{MC} becomes less than Q_{AC} beyond this cross-over frequency. Hence f_{MC} can be considered as the useful bandwidth of the magnetic inductor.

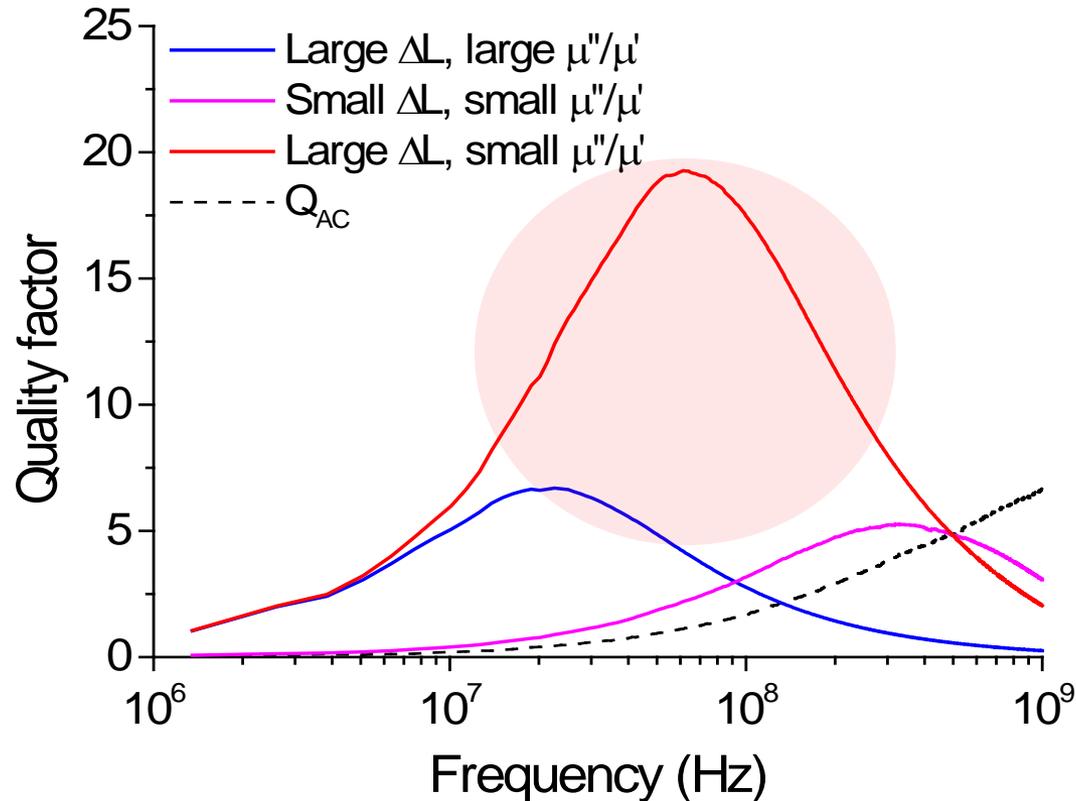
→ **Larger Q values are obtained at lower frequencies for a given magnetic core.**



Ref.: D.W. Lee, K.-P. Hwang, S.X. Wang, IEEE Intl. Magnetics Conf., 2008

Directions for Magnetic Inductors/Transformers

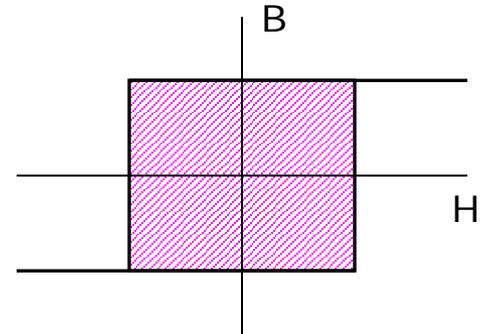
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- The reported device properties tend to have either large ΔL with large μ''/μ' or small ΔL with small μ''/μ' . The case of large ΔL with small μ''/μ' would be desirable to increase the quality factor and the useful bandwidth of the magnetic inductors and transformers.

Materials- Loss Mechanisms

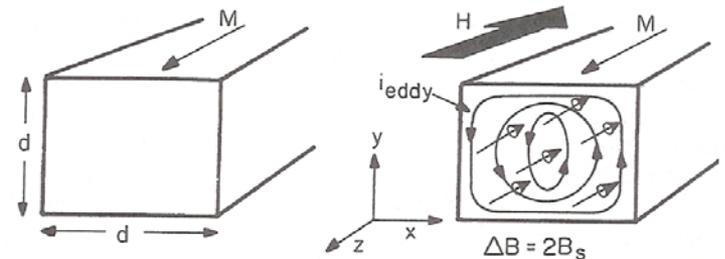
- Hysteresis loss:
 - The area inside the B-H loop is the energy lost per unit volume per cycle
 - Power loss = Frequency x Loop area



- Eddy current loss:
 - The change in the flux density causes the eddy current such that it opposes the initial flux changes
 - Classical eddy current loss:

$$\frac{P_{eddy\ current}}{vol} = \frac{\omega^2 B_m^2 d^2}{48\rho}$$

- Ferromagnetic resonance loss:
 - Imaginary permeability significantly increases as the operation frequency approaches the FMR frequency.



Materials- Theory of Laminations

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- u' 2.8um
- u'' 2.8um
- u' 1um measured
- u'' 1um measured
- u' 1um
- u'' 1um
- u'(FMR without eddy)
- u''(FMR without eddy)

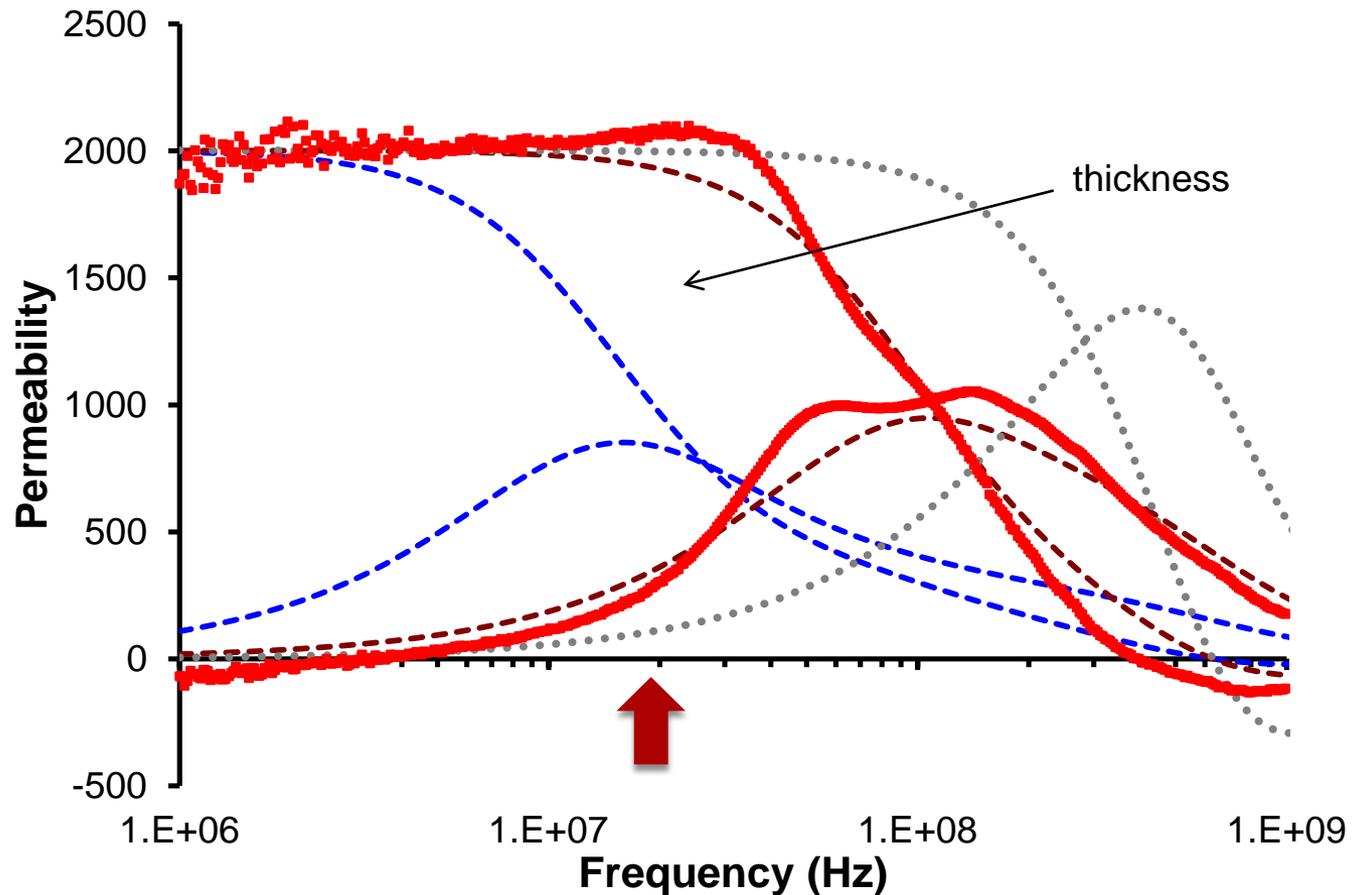
Fitting Equations:

$$\delta = \frac{1}{\sqrt{\pi \sigma \mu_i \mu_0 f}}$$

$$\mu_r = \mu_i \frac{(1-i) e^{(1+i)d/\delta} - 1}{d/\delta e^{(1+i)d/\delta} + 1}$$

$$\mu_i = \mu' - i\mu''$$

$$= \frac{\omega_m (\omega_k + \omega_m + i\omega\alpha)}{(\omega_k + i\omega\alpha)(\omega_k + \omega_m + i\omega\alpha) - \omega^2} + 1$$

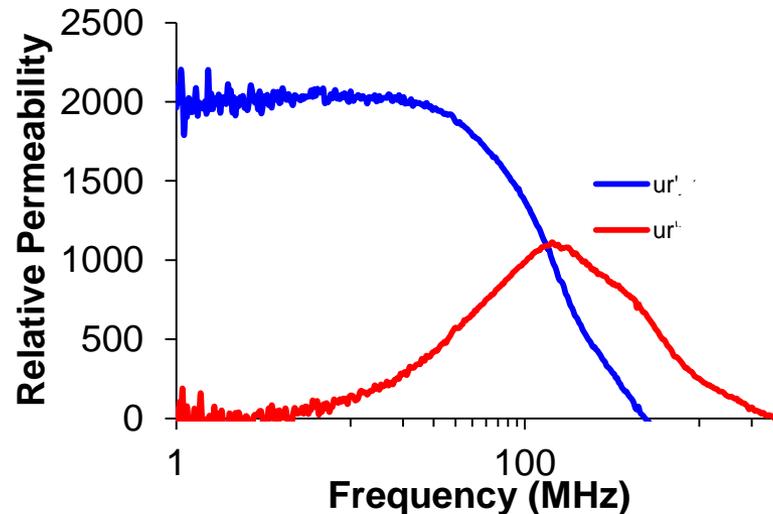
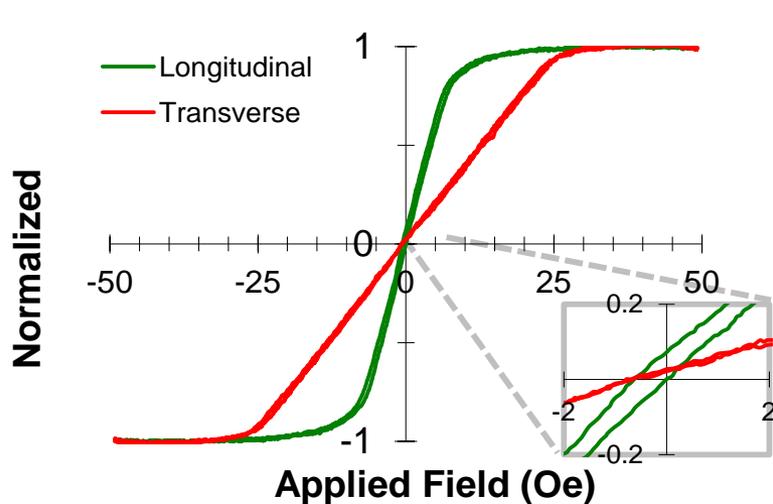
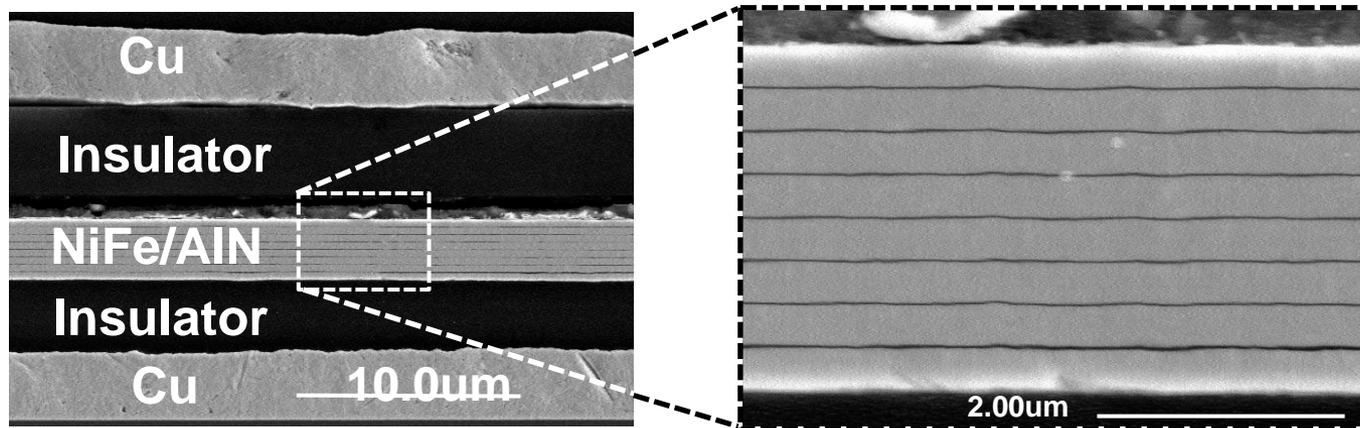


Ref: E. V. D. Riet and F. Roozeboom *J. Appl. Phys.*, vol. 81, Jan. 1997.

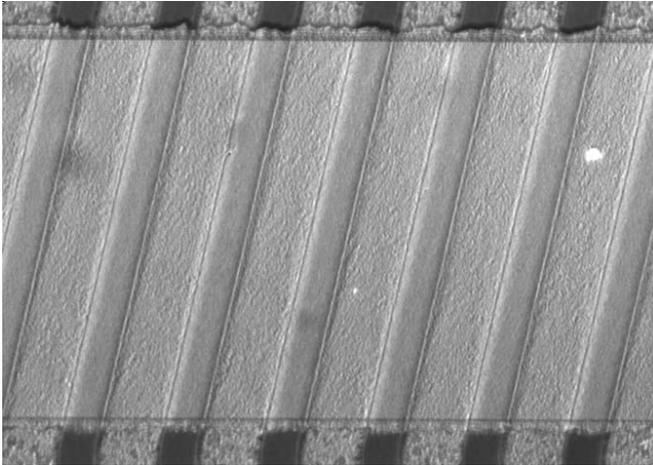
Fabricated Laminated Film

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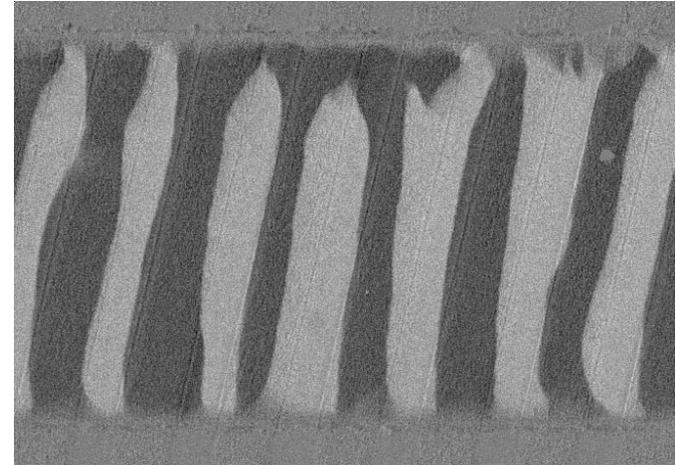
- Properties measured on sample fabricated on the wafer



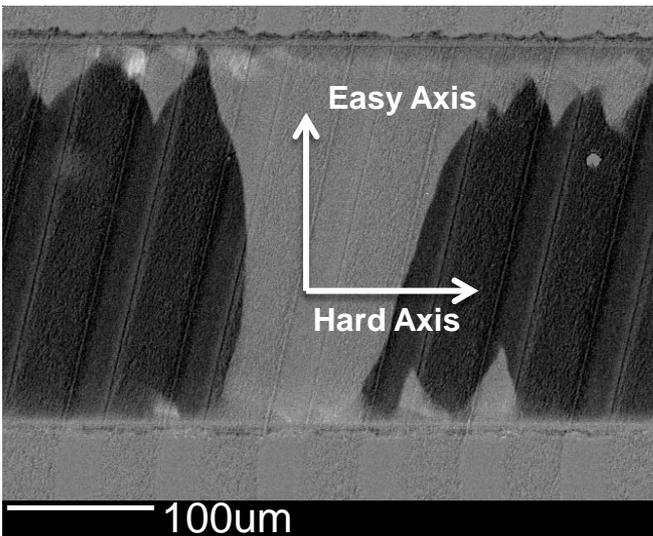
Kerr Domain Images



Background Image



Kerr Image – Hard Axis Excitation



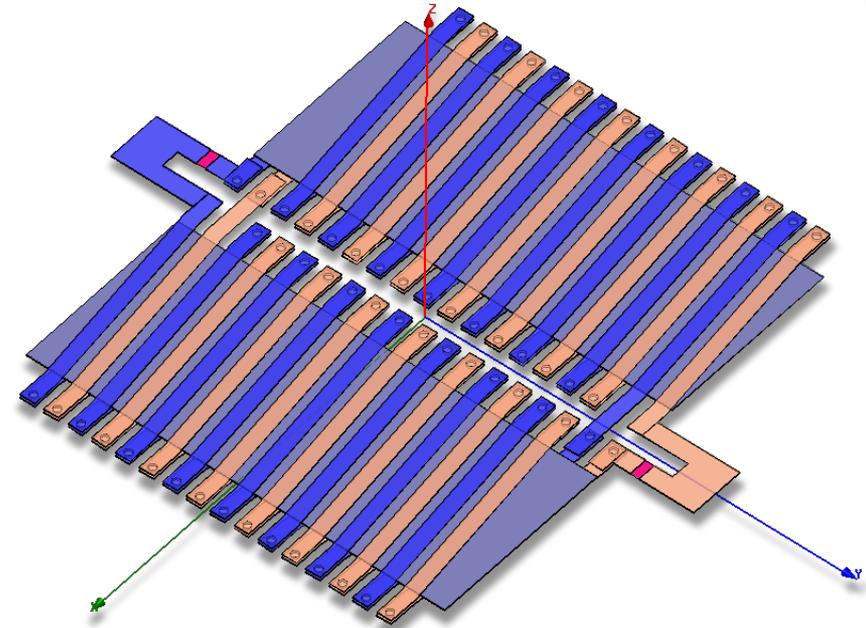
Kerr Image – Easy Axis Excitation

- For operation, field is applied along the hard axis
- Domain patterns are not affected by the underlying coil patterning

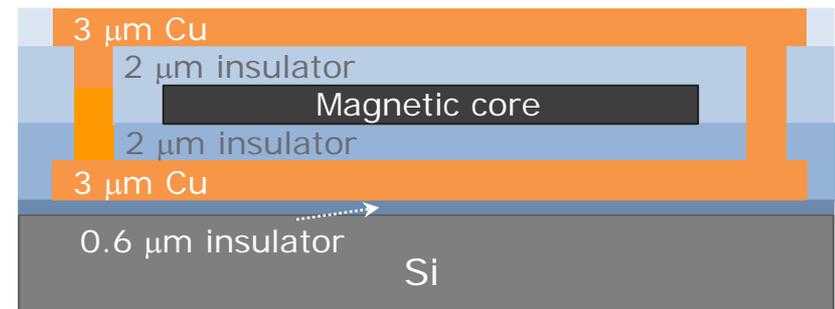
Device Design

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- Solenoid-style transformer
 - ▣ Interleaved coils, 2 series
 - ▣ 4/8/16 turns per series
- Cu coils
 - ▣ 40 μm wide, 3 μm thick
- $\text{Ni}_{81}\text{Fe}_{19}$ Core
 - ▣ $[\text{NiFe}_{(350\text{nm})}/\text{AlN}_{(7\text{nm})}]_8$
 - ▣ 2.8/5.6 μm thick
 - ▣ 150/300/500 μm wide
- Vias
 - ▣ 7 μm total thickness
 - ▣ 2 μm below core, 2 μm above
 - ▣ 30 μm diameter



16 Turn Transformer
500 μm wide core

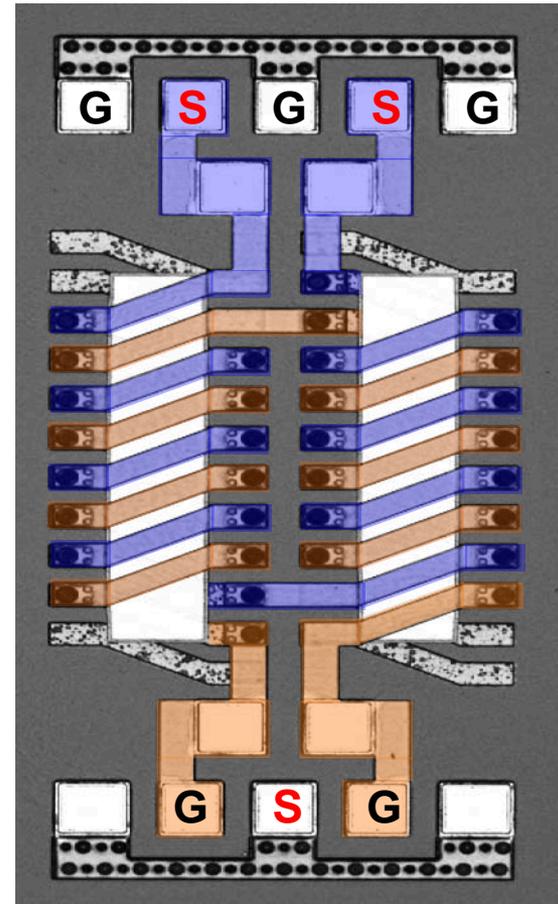


Measurement Methods

- 2-Port Measurement
 - ▣ Measure primary with secondary open
 - ▣ Measure primary with secondary short
 - ▣ Remove pad parasitics using open-short de-embedding structures

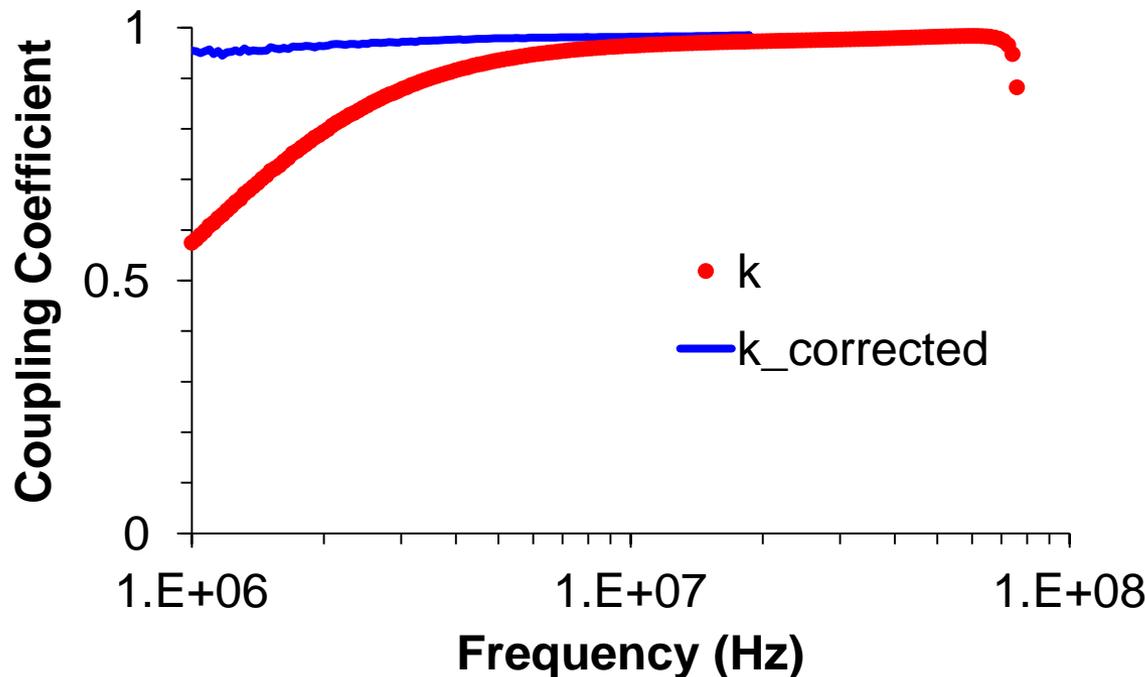
For $L_1=L_2$, and $Q \gg 1$:

$$k \approx \sqrt{1 - \frac{L_{open}}{L_{short}}}$$



Coupling Coefficient- Correction

- Measured device has 300 um wide x 5.6 um thick core, with 32 turns (16 turns per solenoid)
- $k = 0.97$ at 20 MHz (peak Q without the correction)

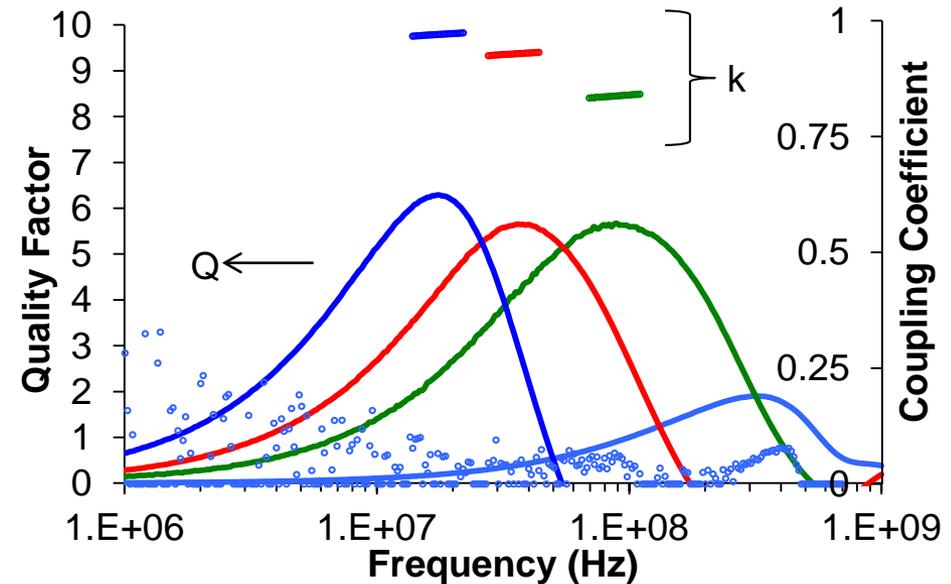
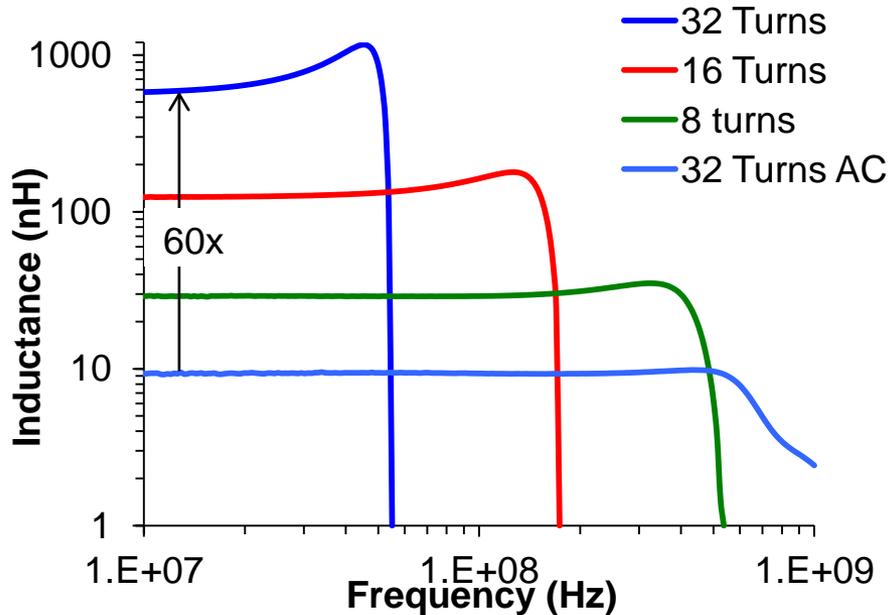


For Finite Q:

$$k_{corrected} = \sqrt{\left(1 - \frac{L_{short}}{L_{open}}\right) \left(\frac{1 + Q^2}{Q^2}\right)}$$
$$= \sqrt{k \left(\frac{1 + Q^2}{Q^2}\right)}$$

Device Properties vs. N

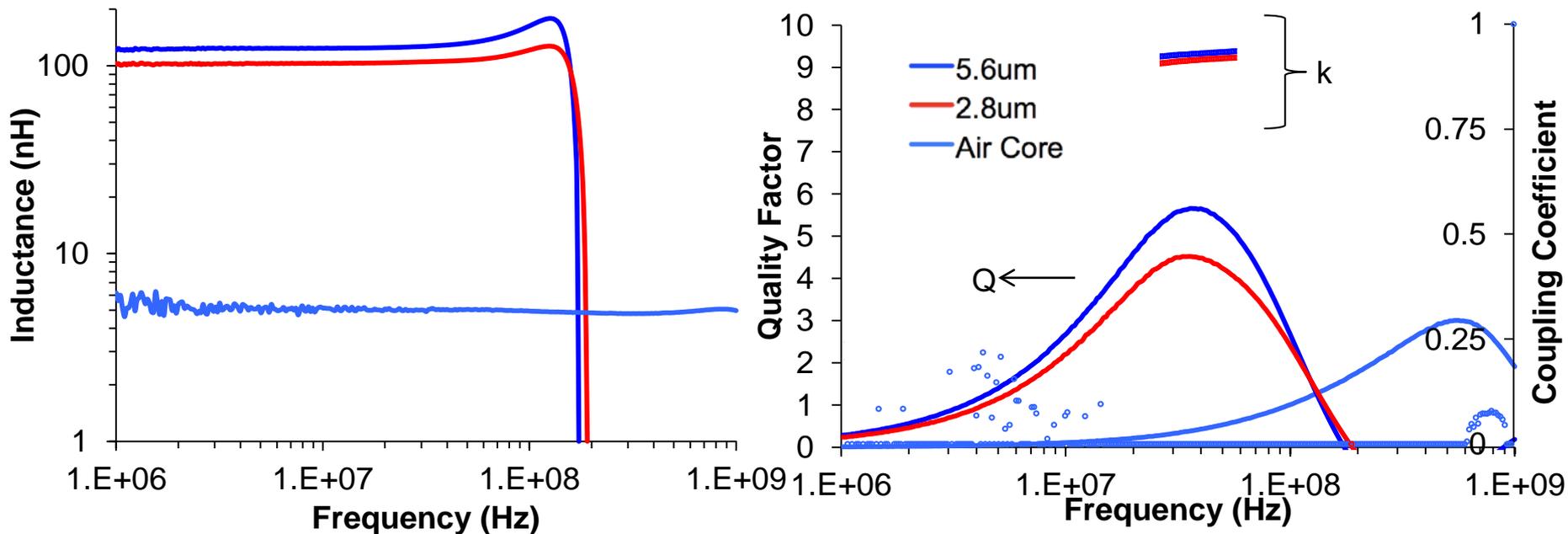
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- All devices have: 500 um wide x 5.6 um thick core, two coils in series
- Coupling coefficient is measured at Q_{peak} without correction
- **32-turn transformer has inductance enhancement by 60x over air-core, and a nearly perfect coupling coefficient at 0.97**
- Air core device had negligible coupling across frequency

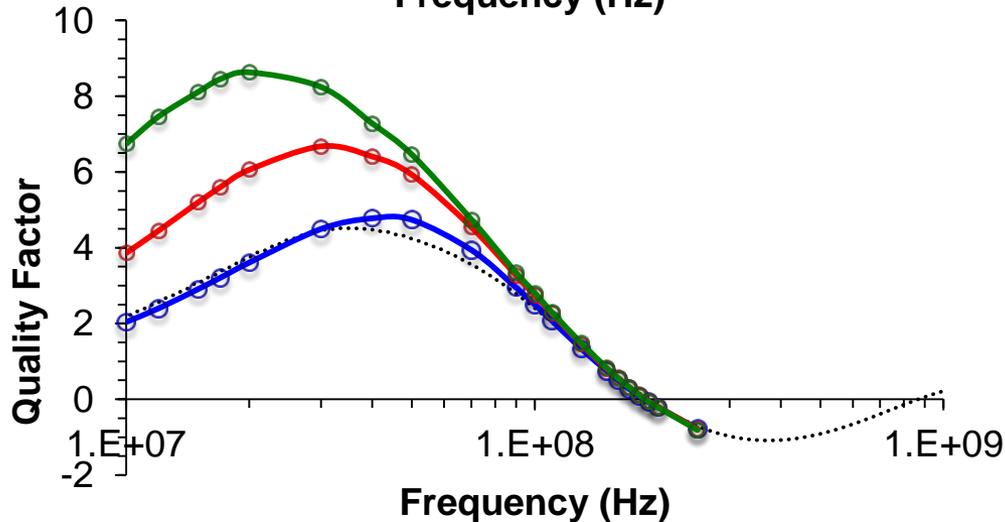
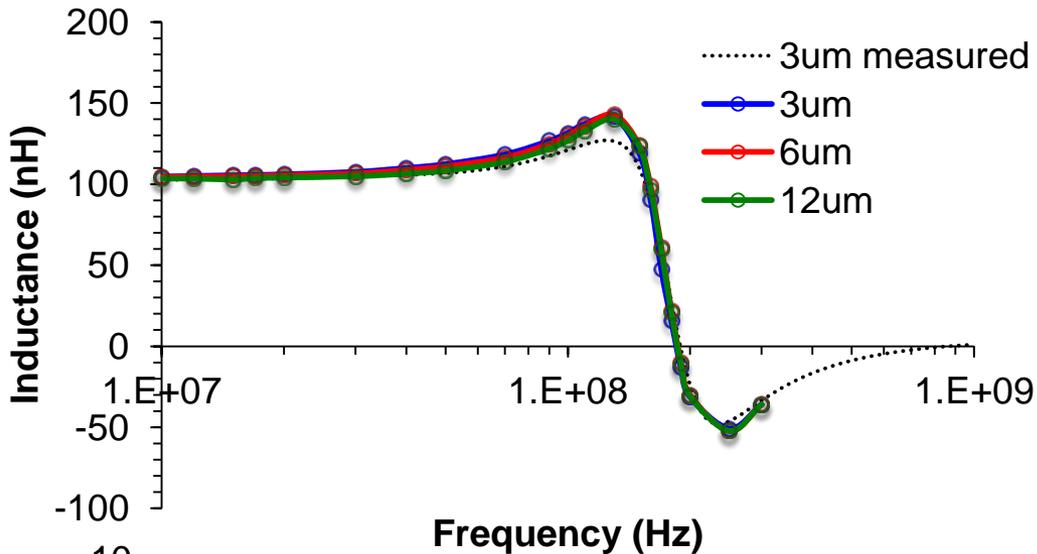
Device Properties vs. Film Thickness

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- All devices have: 500 um wide core with 16 turns, two coils in series (8 turns per solenoid)
- **Thicker core leads to more enhancement in inductance. Inductance enhancement in 16-turn transformer ($>\sim 20x$) is more limited by the demagnetization field than that in 32-turn transformer ($>\sim 60x$).**

Device Properties vs. Coil Thickness



- Thicker coils do not change inductances, but can increase the quality factor for slightly lower frequencies
- High frequency quality factor is determined by magnetic core losses and the AC losses in Cu coils:

$$Q_{MC} = \omega \frac{L_{MC}}{R_{MC}} = \omega \frac{L_{AC} + \Delta L}{R_{AC} + \omega \left(\frac{\mu''}{\mu'} \right) \Delta L}$$

- Quality factor is also limited by the LC resonance.

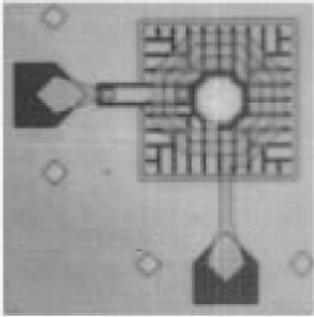
Conclusion

- **High-performance integrated magnetic transformers were successfully designed and fabricated:**
 - **Inductance enhancement** of 60× over the air core equivalent, the **inductance density** reached 178 nH/mm², and a peak **quality factor** of 6.3.
 - **Compact thin film transformers** with coupling efficiency >0.97
- **Analytical and numerical models can accurately describe the actual device properties:**
 - The fundamental trade-offs (**ΔL vs ΔR**) of the integrated magnetic inductors and transformers can be well understood and utilized for optimal design.
 - **Magnetic materials selection and characterization by permeameter and Kerr microscope** are important for device design and experimental trouble shooting.

Backup Slides

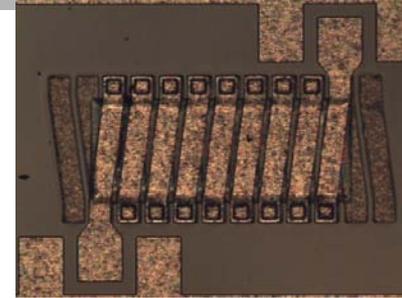


Magnetic Inductors/Transformers for Power Conversion Fabricated by Stanford Collaboration



A.M. Crawford, et al.
IEEE Trans. Magn.
2002, p.3168-70

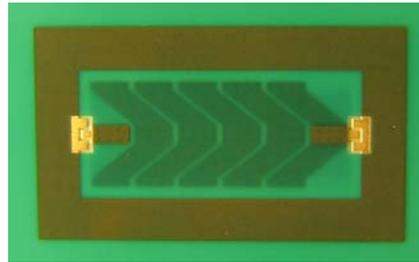
**Planar spiral inductor
with CoTaZr core,
CMOS compatibility,
 $Q \sim 2.7$ @ 1 GHz**



D. W. Lee, et al.

IEEE Trans. Mag., 44, 4089-95, 2008

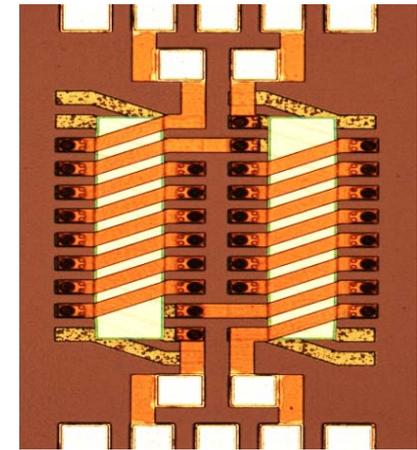
**Planar solenoid inductor with
CoTaZr core,
Inductance enhancement over
air core = 34x
 $Q > 6$ @ 26 MHz**



L. Li, D. W. Lee, et al.

IEEE Trans. Advanced Packaging,
32(4), 780-787, 2009

**On-package solenoid
inductor with CoFeHfO core,
 $Q = 22$ @ 200~300 MHz,
 $R_{dc} \sim 10$ m Ω**



**Magnetic transformers
with laminated NiFe/AlN
cores**